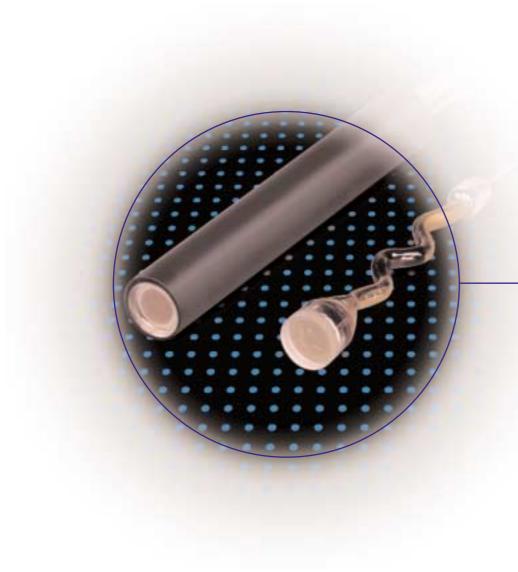
Imaging Telecom

Channel Photomultipliers

Channel Photomultipliers Overview and Specifications





CHANNEL PHOTOMULTIPLIER







Features

- Ultra high anode sensitivity up to 10⁷ A/W
- Extremely low dark current, typically 3pA @ 10⁶ gain
- Very low equivalent noise input (down to 10⁻¹⁷ W)
- Very high stability in dark current (no "bursts")
- High gain exceeding 10⁸
- Very high dynamic range
- Compact dimensions
- Wide spectral response through multiple window materials
- High resolution
- Fast response time
- High immunity to magnetic fields
- Rugged design

Description

PerkinElmer Optoelectronics, formerly EG&G Optoelectronics, is pleased to introduce the Channel Photomultiplier (CPM), a new ultra high sensitivity optical detector which replaces conventional photomultipliers (PMTs) and avalanche photo diodes (APDs). This device uses a unique detector principle, resulting in a compact design with ultra high gain, high dynamic range, extremely low dark current, and fast response.

This high-performance detector offers fundamental advantages for analytical instrumentation applications such as emission spectroscopy, flourescence, atomic absorption spectroscopy, and bio and chemo luminescence. The CPM also delivers important advantages in life science products, industrial and medical equipment, and highenergy physics.

When compared to conventional PMTs, the CPM improves anode sensitivity by one order of magnitude, while lowering dark current by one to two orders of magnitude. The noise level shows extreme stability over time, with no "bursts." The extremely low dark current results in a higher dynamic range than conventional PMTs and extends detectable limits for many applications.

The CPM can be used in analog-DC mode, single photon counting mode, and in nuclear spectroscopy (when coupled to scintillation materials like BGO, LSO, Nal, etc.). PerkinElmer Optoelectronics offers a choice of window materials and photocathodes to cover the spectrum from 115 nm (UV range) to 900 nm (NIR).

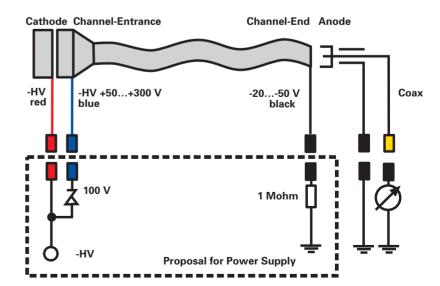
The new detector is a small, head-on type with a total diameter of 10.5 mm including encapsulation. PerkinElmer Optoelectronics also offers custom configurations for specific applications.

PRINCIPLE OF OPERATION

Principle of Operation

The CPM, like conventional photomultiplier tubes, converts a very low light level into photoelectrons by a semitransparent photocathode deposited on the inner surface of the entrance window. On their way from the cathode to the anode the photoelectrons pass through a narrow, semiconductive channel. Each time the electrons hit the inner wall of the curved channel, multiple secondary electrons are emitted. This effect occurs multiple times along the path, leading to an avalanche effect with a gain exceeding 108. The curved shape of the glass tube improves the multiplication effect.

Physical Specification

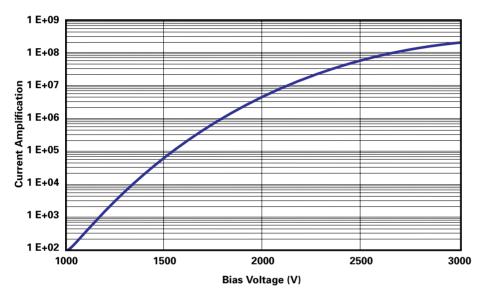


MAIN FEATURES



Unpotted 1/3 inch Channel Photomultiplier

Fig. 1: Typical current amplification



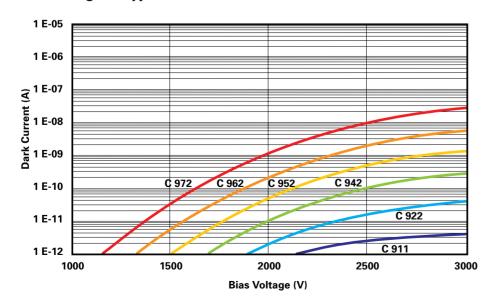
Compact Size

The CPM is one of the smallest headon type detectors, with a 10.5 mm diameter including encapsulation. The photocathode has a useful diameter of more than 5 mm. The tube is smaller, easier to use, and more rugged than discrete dynode types. Only a single high voltage supply of up to 3000 volts is necessary; no external voltage divider network is required. A variety of different sizes will be available soon (1/2" and 3/4").

Ultra high anode sensitivity

At the maximum bias voltage of 3000 V, gains can exceed 10°. At 2400 V, anode sensitivity is typically 3 x 10° AWV at a wavelength of 410 nm with a bialkali photocathode. This performance surpasses conventional PMTs by one to two orders of magnitude and beats APDs by approximately five orders of magnitude (Fig. 1).

Fig. 2: Typical anode dark current



Extremely low dark current

The electron multiplication in the channel is virtually silent, so dark current depends only on the photocathode material, leakage currents are negligible. Bialkali photocathodes exhibit typical dark count rates of 10 cps at a gain of 3 x 108, while UV cathodes have dark count rates below 1 cps. In analog DC mode, the typical dark noise for a bialkali photocathode is 20 pA at a gain of 107. In general, the noise level of the PerkinElmer Optoelectronics CPM is one to two orders of magnitude lower than dynode PMTs, resulting in a significantly higher dynamic range (Fig.2).

High stability in dark current level

As a result of the semiconductive inner surface of the CPM, no charge-up effects occur at the glass surface. This results in a very high stability of the dark current level over time, with no sudden changes (bursts). The semiconductive surface also causes high-light recovery times to be extremely small.

Fig. 3: Typical photo electron spectrum

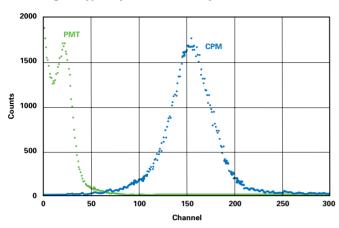


Fig. 4.1: Typical spectral response

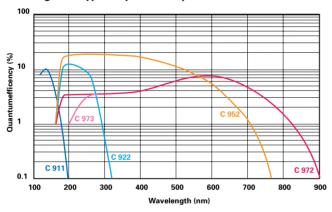
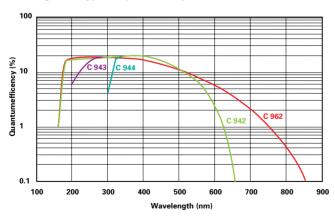


Fig. 4.2: Typical spectral response



EU PerkinElmer Optoelectronics GmbH Heimann Opto

65020 Wiesbaden, Germany PO-Box 3007 http://www.perkinelmer.com/opto

USA PerkinElmer Optoelectronics 2175 Mission College Blvd. Santa Clara CA 95054

Santa Clara, CA 95054 Tel. ++1 (408) 565 - 0830 Fax ++1 (408) 565 - 0703 http://www.perkinelmer.com/opto

Excellent photon counting resolution

At gains exceeding 10⁷ the single photo electron pulse is perfectly separated from the electrical noise, due to a saturation effect of the channel. The CPM exhibits single photon resolution with excellent peak to valley ratios. Fig. 3 shows the single photo electron spectrum taken from a multi-channel analyzer compared to a conventional photomultiplier (Fig. 3).

Choice of entrance window

The CPM is available with different window materials, which are:

MgF₂, Quartz, UV-glass, and Borosilicate glass. The combination of different photocathodes and entrance windows results in a spectral range from 115 nm to 900 nm. Other window materials and photocathode combinations are available on a custom basis (Fig. 4.1 and 4.2).

Available related products

High Voltage supply

CHV 30N (supplies 1 CPM, negative output voltage), CHV 30P (supplies 1 CPM, positive output voltage), J4-3N (supplies 10 to 15 CPMs)

CPM Modules

MP900-series: Photoncounting module with

TTL output, including CPM, electronic and high voltage

MD900-series: DC module including high

voltage supply, amplifier, I/U converter, output 0 to 10 V,

bandwidth 1kHz

MH900-series: High voltage module,

including CPM and

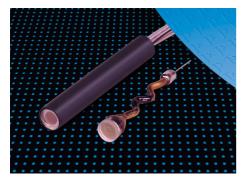
high voltage power supply

CPM Formats

1/₃" C900-series 1/₂" C1300-series 3/₄" C1900-series

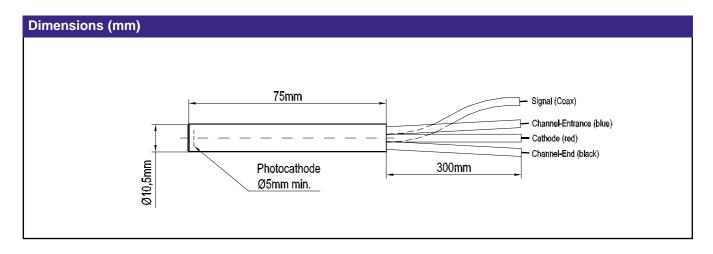
Datasheets on request

1/3" CPM Channel Photomultipliers



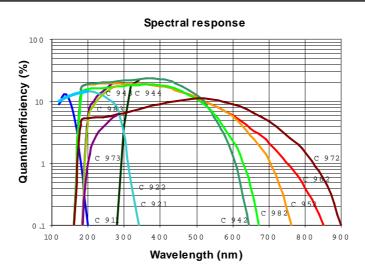
- · High Sensitivity Optical Detector
- · Extremely High Gain
- · Ultra Low Noise
- · 1/3 Inch, Head-On Type

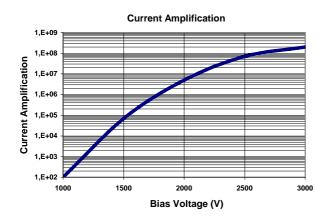
Technical Specifications																									
Туре	Spectral response (nm)	Photocathode material	Min. useful area (mm)	Window material	Electron multiplication	Supply voltage (V)	Current amplification	@ 140 nm (A/W)	@ 200 nm (A/W)	@ 400 nm (A/W)	@ 560 nm (A/W)	Dark current (pA)	Equivalent Noise Input, ENI (W)	Bias current (µA)	Max. linear anode current	Max. anode current*	Response time Rise time (ns) Pulse width / FWHM (ns)	Special types for Photon Counting	Supply voltage (V)	Single photo electron gain	Dark counts (cps)	Peak to valley	Max. ambient temperature (°C)		
													17												
C911	115-200	Csl		MgF ₂				6x10 ⁵			-	2	1x10 ⁻¹⁷					C911P			0.1				
C921	115-320	CsTe		MgF ₂	-				x10 ⁶ x10 ⁶			10 10	1x10 ⁻¹⁷					C921P C922P			1				
C922 C942	165-320 165-650	CsTe :=		Quartz Quartz			5x10 ⁷					3x10 ⁶		80	1x10 ⁻¹⁷ 1x10 ⁻¹⁷					C922P			10		
C943	185-650	Bial kali		UV glass								3x10 ⁶		80	1x10 ⁻¹⁷		ent			C943P			10		
C944	300-650	Bia		Borosil.							3x10 ⁶		80	1x10 ⁻¹⁷		curr			C944P			10			
C952	165-750	Low noise Multialk.		Quartz	Channel Electron Multiplier	(00					3x10 ⁶		250	2.5x10 ⁻¹⁷		of bias	C952P			40					
C953	185-750	Low noise Multialk.	5	UV glass	tron N	(max. 3000				3x10 ⁶		250	2.5x10 ⁻¹⁷	20	10% of bias current	30	93	C953P	3000)	3x10 ⁸	40	10:1	50		
C962	165-850	Multialk.	4,	Quartz	Elec					2x	10 ⁶	1000	4x10 ⁻¹⁷	5	50 arity limit) 10 10 µA (max.		C962P	(max. 3	,×	100	10	5			
C963	185-850	Mu		UV glass	anne	2400				2x	10 ⁶	1000	4x10 ⁻¹⁷		arity	10 µ		C963P			100				
C972	165-900	Extend. red Multialk.		Quartz	ਤੌਂ							5000			(DC linearity limit)			C972P	3000		500				
C973	185-900	Ext.		UV glass						2x	10 ⁶	5000	1.5x10 ⁻¹⁶		Ō			C973P			500				
C982	165-650	se ≷		Quartz							3x10 ⁶		25	6x10 ⁻¹⁸					C982P			3			
C983	185-650	Low noise Bialk.		UV glass						3x10 ⁶		25	6x10 ⁻¹⁸					C983P			3				

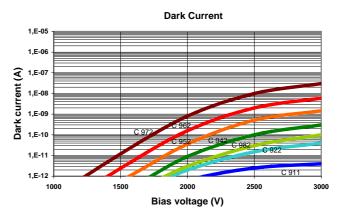


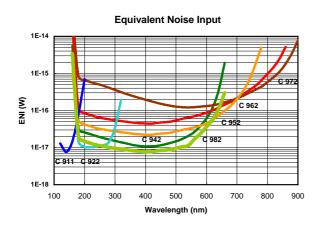
CPM C900 Series1/3" **CPM Channel Photomultipliers**

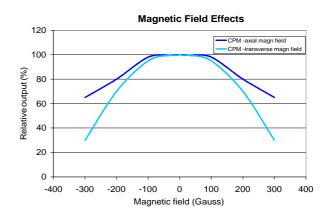










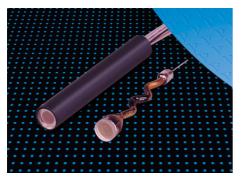


CAUTION: High Voltage Warning!

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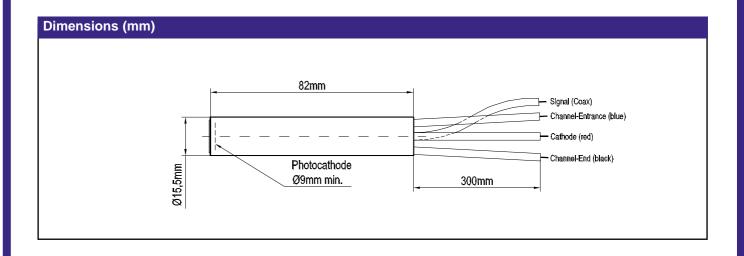
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CPM C1300 Series1/2" **CPM Channel Photomultipliers**



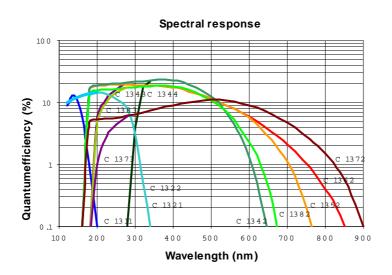
- · High Sensitivity Optical Detector
- · Extremely High Gain
- · Ultra Low Noise
- · 1/2 Inch, Head-On Type

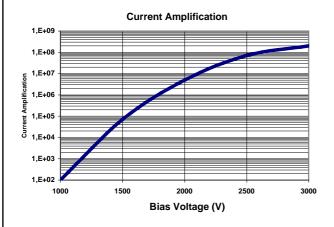
Techr	nical Sp	ecifica	atio	ons																		
Туре	Spectral response (nm)	Photocathode material	Min. useful area (mm)	Window material	Electron multiplication	Supply voltage (V)	Current amplification	@ 140 nm (A/W)	@ 200 nm (A/W)	@ 560 nm (A/W)	Dark current (pA)	Equivalent Noise Input, ENI (W)	Bias current (µA)	Max. linear anode current	Max. anode current*	Response time Rise time (ns) Pulse width / FWHM (ns)	Special types for Photon Counting	Supply voltage (V)	Single photo electron gain	Dark counts (cps)	Peak to valley	Max. ambient temperature (°C)
								5				a 1a-17										\perp
C1311	115-200	Csl		MgF ₂				6x10 ⁵	4.0fi	8		2x10 ⁻¹⁷					C1311P			0.4		
C1321	115-320	CsTe		MgF ₂					10 ⁶		40 40	2x10 ⁻¹⁷ 2x10 ⁻¹⁷					C1321P C1322P	+		4		
C1322 C1342	165-320 165-650	CsTe :=		Quartz Quartz				IX.	3x10	n ⁶	320	2x10 2x10	-			C1342P			40			
C1342	185-650	Bial kali		UV glass					3x10		320	2x10 ⁻¹⁷		ent			C1342P			40		
C1344	300-650	Bia		Borosil.						3x10		320	2x10 ⁻¹⁷		curr			C1344P			40	
C1352	165-750	Low noise Multialk.		Quartz		3000)			3x10		1000	4x10 ⁻¹⁷		(DC linearity limit) 10% of bias current	sec.)		C1352P	3000)		160		
C1353	185-750	Low		UV glass			0,		3x10) ⁶	1000	4x10 ⁻¹⁷		%0	. 30		C1353P		08	160	-	
C1362	165-850	Multialk.	6	Quartz		2400 (max.	5x10 ⁷			2x10 ⁶	4000	00 8x10-17 0C 0T Xem W		10 µA (max. 30 sec.)	r 9	C1362P	(max. 3	3x10 ⁸	400	10:1	90	
C1363	185-850	Mu		UV glass		240				2x10 ⁶	4000	8x10 ⁻¹⁷		arity	10 µ		C1363P	00		400		
C1372	165-900	Extend. red Multialk.		Quartz						2x10 ⁶	20000	3x10 ⁻¹⁶		C line			C1372P	3000		2000	ĺ	
C1373	185-900	Ex r Mu		UV glass						2x10 ⁶	20000	3x10 ⁻¹⁶					C1373P			2000		
C1382	165-650	Low noise Bialk.		Quartz						3x10	O ⁶	100	1x10 ⁻¹⁷			C1382P			10			
C1383	185-650	Lc noi Bia		UV glass					3x10	O ⁶	100	1x10 ⁻¹⁷					C1383P			10		

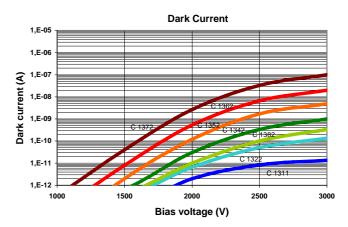


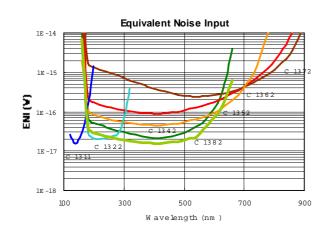
CPM C1300 Series 1/2" CPM Channel Photomultipliers

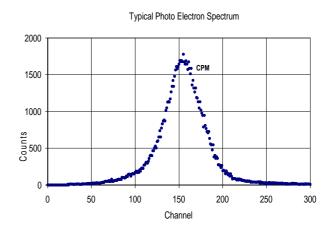










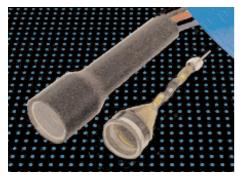


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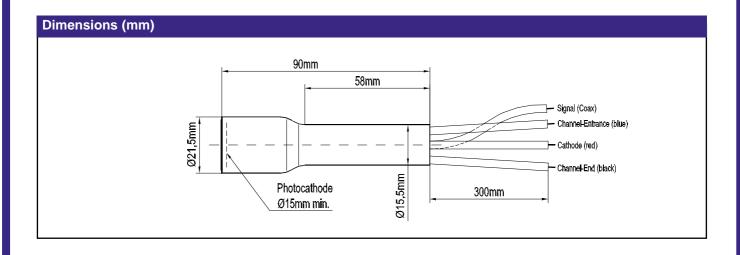
All given values are nominal/typical @ 20 °C ambient temperature; specifications subject to change without notice.

CPM C1900 Series 3/4" **CPM Channel Photomultipliers**



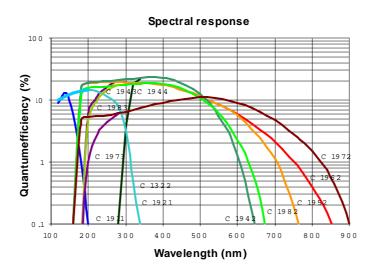
- · High Sensitivity Optical Detector
- · Extremely High Gain
- · Ultra Low Noise
- · 3/4 Inch, Head-On Type

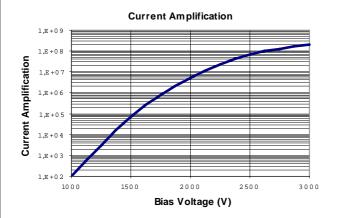
Techi	nical Sp	ecifica	atio	ons																										
Туре	Spectral response (nm)	Photocathode material	Min. useful area (mm)	Window material	Electron multiplication	Supply voltage (V)	Current amplification	@ 140 nm (A/W)	@ 200 nm (A/W)	@ 400 nm (A/W)	Dark current (pA)	Equivalent Noise Input, ENI (W)	Bias current (µA)	Max. linear anode current	Max. anode current*	Response time Rise time (ns) Pulse width / FWHM (ns)	Special types for Photon Counting	Supply voltage (V)	Single photo electron gain	Dark counts (cps)	Peak to valley	Max. ambient temperature (°C)								
												47																		
C1911	115-200	Csl		MgF ₂				6x10 ⁵			20	3x10 ⁻¹⁷					C1911P			1										
C1921	115-320	CsTe		MgF ₂					x10 ⁶		100	3x10 ⁻¹⁷					C1921P			10										
C1922	165-320	CsTe		Quartz				1)	x10 ⁶	κ10 ⁶	100 800	3x10 ⁻¹⁷ 3x10 ⁻¹⁷					C1922P C1942P			10										
C1942 C1943	165-650 185-650	Bial kali		Quartz								κ10 ⁶	800	3x10	1	t i			C1942P		ı	100								
C1943	300-650	Bial		UV glass Borosil.	L														k10 ⁶	800	3x10 ⁻¹⁷		current			C1943P			100	
C1952	165-750	Low noise Multialk.		Quartz	Channel Electron Multiplier	3000)				3)	۲10 ⁶	2500	8x10 ⁻¹⁷		(DC linearity limit) 10% of bias	30 sec.)		C1952P			400									
C1953	185-750	ુ≥	13	UV glass	tror	ax.	5x10 ⁷		3)	۲10 ⁶	2500	8x10 ⁻¹⁷	20	10%		8 9	C1953P	3000	3x10 ⁸	400	10:1	20								
C1962	165-850	Multialk.	_	Quartz	el Elec	2400 (max. 3000)	5x1			2x10	10000	1x10 ⁻¹⁶	5	limit) '	μΑ (max.	., 0	C1962P	3000 (max. 3	3,	1000	10	2								
C1963	185-850	Σ		UV glass	ann	24				2x10	10000	1x10 ⁻¹⁶		arity	101		C1963P	00		1000										
C1972	165-900	Extend. red Multialk.		Quartz	Š					2x10	50000	5x10 ⁻¹⁶		C line			C1972P	300		5000										
C1973	185-900	Ă-Ē		UV glass							2x10	50000	5x10 ⁻¹⁶		ן בי			C1973P			5000									
C1982	165-650	Low noise Bialk.		Quartz															3)	κ10 ⁶	250	2x10 ⁻¹⁷					C1982P			25
C1983	185-650	ᅵᆵᆿ	J 2 18		UV glass					3>	κ10 ⁶	250	2x10 ⁻¹⁷					C1983P			25									

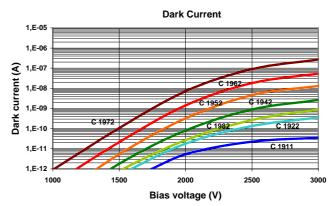


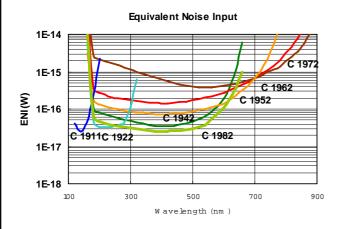
CPM C1900 Series 3/4" CPM Channel Photomultipliers

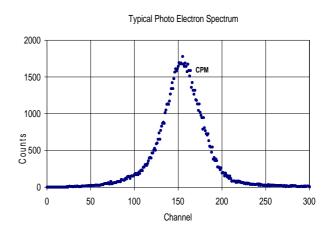












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PerkinElmer Optoelectronics 2175 Mission College Blvd. Santa Clara, CA 95054 Phone: (408) 565-0850 Fax: (408) 565-0793

EUROPE:

PerkinElmer Optoelectronics GmbH Wenzel-Jaksch-Str. 31 65199 Wiesbaden Germany Phone: +49 611 492 534 Fax: +49 611 492 578

ASIA:

PerkinElmer Optoelectronics 47 Ayer Rajah Crescent #06-12 Singapore 139947 Phone: +65 775 2022 Fax: +65 775 1008

